

Heisener.com

MT29F3T08EUHBBM4-3R:B

MT29F3T08EUHBBM4-3R:B Information

Part Number MT29F3T08EUHBBM4-3R:B

Manufacturer Micron Technology Inc. Category Integrated Circuits (ICs)

Memory

Description IC FLASH 3T PARALLEL 333MHZ

Package

For the pricing/inventory/lead time, please contact

Website: https://www.heisener.com For Reference Only

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









MT29F3T08EUHBBM4-3R:B Specifications

Manufacturer Part Number	MT29F3T08EUHBBM4-3R:B
Manufacturer	Micron Technology Inc.
Category	Integrated Circuits (ICs)
	Memory
Package	-
Series	-
Memory Type	Non-Volatile
Memory Format	FLASH
Technology	FLASH - NAND
Memory Size	3Tb (384G x 8)
Memory Interface	Parallel
Clock Frequency	333MHz
Write Cycle Time - Word, Page	-
Access Time	-
Voltage - Supply	2.5 V ~ 3.6 V
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	-
Package / Case	-
Supplier Device Package	-
	Report errors?

MT29F3T08EUHBBM4-3R:B Guarantees



Ouality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

MT29F3T08EUHBBM4-3R:B Payment Methods





















MT29F3T08EUHBBM4-3R:B Shipping Methods













If you have any question about MT29F3T08EUHBBM4-3R:B, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com